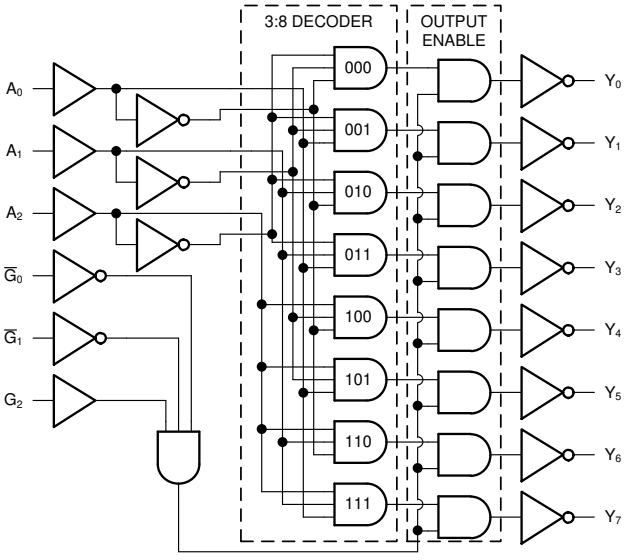
TEXAS INSTRUMENTS
CD54HC138, CD74HC138, CD54HCT138, CD74HCT138, CD54HC238, CD74HC238, CD54HCT238, CD74HCT238
JAJSNC7J – NOVEMBER 1998 – REVISED NOVEMBER 2021

CDx4HC138、CDx4HCT138、CDx4HC238、CDx4HCT238 ハイスピード CMOS ロジック 3～8 ライン・デコーダ / デマルチプレクサ (反転および非反転)

1 特長

- 8 つのデータ出力のいずれかを選択:
  - '138 はアクティブ LOW
  - '238 はアクティブ HIGH
- I/O ポートまたはメモリ・セレクタ
- カスケード接続を簡単にするための 3 つのイネーブル入力
- 13ns の伝搬遅延 (標準値、V_{CC} = 5V、C_L = 15pF、T_A = 25℃)
- ファンアウト (全温度範囲にわたって)
  - バス・ドライバ出力:15 の LSTTL 負荷
  - 標準出力:10 の LSTTL 負荷
- 広い動作温度範囲:-55℃～125℃
- 平衡な伝搬遅延と遷移時間
- LSTTL ロジック IC に比べて消費電力を大幅削減
- HC タイプ
  - 2V～6V で動作
  - 優れたノイズ耐性:N_{IL} = V_{CC} の 30%、N_{IH} = V_{CC} の 30% (V_{CC} = 5V の場合)
- HCT タイプ
  - 4.5V～5.5V で動作
  - LSTTL 入力ロジックと直接互換、V_{IL} = 0.8V (最大値)、V_{IH} = 2V (最小値)
  - CMOS 入力互換、V_{OL}、V_{OH} で $I_I \le 1\mu A$



機能ブロック図 '138

2 概要

CDx4HC(T)138 および '238 は、1 つの通常の (アクティブ HIGH) 出力ストローブ (G_2) と 2 つのアクティブ LOW 出力ストローブ ($\overline{G}_1$、$\overline{G}_0$) を備えた 3～8 デコーダです。いずれかのストローブ入力により出力が無効化されると、すべての出力は HIGH 状態に強制されます。ストローブ入力により出力が無効化されている場合以外は、選択された出力のみが LOW であり、その他のすべての出力は HIGH です。

CDx4HC(T)238 は、1 つの通常の (アクティブ HIGH) 出力ストローブ (G_2) と 2 つのアクティブ LOW 出力ストローブ ($\overline{G}_1$、$\overline{G}_0$) を備えた 3～8 デコーダです。いずれかのストローブ入力により出力が無効化されると、すべての出力は LOW 状態に強制されます。ストローブ入力により出力が無効化されている場合以外は、選択された出力のみが HIGH であり、その他のすべての出力は LOW です。

製品情報

部品番号	パッケージ (1)	本体サイズ (公称)
CD74HC138E	PDIP (16)	25.40mm × 6.35mm
CD74HCT138E	PDIP (16)	25.40mm × 6.35mm
CD74HCT238E	PDIP (16)	25.40mm × 6.35mm
CD74HC138M	SOIC (16)	9.90mm × 3.90mm
CD74HCT238M	SOIC (16)	9.90mm × 3.90mm
CD74HC238NS	SO (16)	10.20mm × 5.30mm
CD74HC238PW	TSSOP (16)	5.00mm × 4.40mm
CD74HCT238PW	TSSOP (16)	5.00mm × 4.40mm
CD54HC138F	CDIP (16)	21.34mm × 6.92mm
CD54HCT138F	CDIP (16)	21.34mm × 6.92mm
CD54HCT238F	CDIP (16)	21.34mm × 6.92mm

(1) 利用可能なすべてのパッケージについては、このデータシートの末尾にある注文情報を参照してください。

英語版の TI 製品についての情報を翻訳したこの資料は、製品の概要を確認する目的で便宜的に提供しているものです。該当する正式な英語版の最新情報は、www.ti.com で閲覧でき、その内容が常に優先されます。TI では翻訳の正確性および妥当性につきましては一切保証いたしません。実際の設計などの前には、必ず最新版の英語版をご参照くださいますようお願いいたします。

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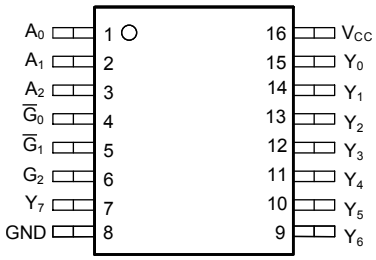
3 Revision History

資料番号末尾の英字は改訂を表しています。その改訂履歴は英語版に準じています。

Changes from Revision I (August 2004) to Revision J (November 2021)	Page
• 最新のデータシート規格を反映するように、文書全体の表、図、相互参照の採番と書式設定を更新	1
• 現行の TI の命名規則に合わせてピン名を以下のように更新。E_3 を G_2、$\overline{E}_2$ を $\overline{G}_1$、$\overline{E}_1$ を $\overline{G}_0$。	1

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4 Pin Configuration and Functions



J, N, D, NS, or PW package
16-Pin CDIP, PDIP, SOIC, SO, or TSSOP
Top View

Pin Functions

PIN		I/O[1]	DESCRIPTION
SOIC or TSSOP NO.	NAME		
1	A_0	I	Address select 0
2	A_1	I	Address select 1
3	A_2	I	Address select 2
4	$\overline{G}_0$	I	Output strobe 0, active low
5	$\overline{G}_1$	I	Output strobe 1, active low
6	G_2	I	Output strobe 2
7	Y_7	O	Output 7
8	GND	—	Ground
9	Y_6	O	Output 6
10	Y_5	O	Output 5
11	Y_4	O	Output 4
12	Y_3	O	Output 3
13	Y_2	O	Output 2
14	Y_1	O	Output 1
15	Y_0	O	Output 0
16	V_{CC}	—	Positive supply

(1) Signal Types: I = Input, O = Output, I/O = Input or Output.

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5 Specifications

5.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)(1)

			MIN	MAX	UNIT
V_{CC}	Supply voltage		-0.5	7	V
I_{IK}	Input clamp diode current	For $V_I < 0.5V$ or $V_I > V_{CC} + 0.5V$		±20	mA
I_{OK}	Output clamp diode current	For $V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$		±20	mA
I_O	Output source or sink current per output pin	For $V_O > -0.5V$ or $V_O < V_{CC} + 0.5V$		±25	mA
	Continuous current through V_{CC} or GND			±50	mA
T_J	Junction temperature			150	°C
T_{stg}	Storage temperature range		-65	150	°C
	Lead temperature (Soldering 10s) (SOIC - Lead Tips Only)			300	°C

(1) Stresses beyond those listed under *absolute maximum ratings* may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under *recommended operating conditions* is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

5.2 Recommended Operating Conditions

			MIN	MAX	UNIT
V_{CC}	Supply voltage range	HC types	2	6	V
		HCT types	4.5	5.5	
V_I	Input voltage		0	V_{CC}	V
V_O	Output voltage		0	V_{CC}	V
t_t	Input rise and fall time	V_{CC} = 2V		1000	ns
		V_{CC} = 4.5V		500	
		V_{CC} = 6V		400	
T_A	Temperature range		-55	125	°C

5.3 Thermal Information

THERMAL METRIC		CD74HC(T)138, CD74HC(T)238				UNIT
		N (PDIP)	D (SOIC)	NS (SOP)	PW (TSSOP)	
		16 Pins	16 Pins	16 Pins	16 Pins	
$R_{\theta JA}$	Junction-to-ambient thermal resistance(1)	67	73	64	108	°C/W

(1) For more information about traditional and new thermal metrics, see the Semiconductor and IC package thermal metrics application report.

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5.4 Electrical Characteristics

PARAMETER		TEST CONDITIONS[1]	V_{CC}(V)	25°C			-40°C to 85°C		-55°C to 125°C		UNIT
				MIN	TYP	MAX	MIN	MAX	MIN	MAX	
HC TYPES											
V_{IH}	High-level input voltage		2	1.5			1.5		1.5		V
			4.5	3.15			3.15		3.15		V
			6	4.2			4.2		4.2		V
V_{IL}	Low-level input voltage		2			0.5		0.5		0.5	V
			4.5			1.35		1.35		1.35	V
			6			1.8		1.8		1.8	V
V_{OH}	High-level output voltage	I_{OH} = – 20 µA	2	1.9			1.9		1.9		V
		I_{OH} = – 20 µA	4.5	4.4			4.4		4.4		V
		I_{OH} = – 20 µA	6	5.9			5.9		5.9		V
	High-level output voltage	I_{OH} = – 4 mA	4.5	3.98			3.84		3.7		V
		I_{OH} = – 5.2 mA	6	5.48			5.34		5.2		V
V_{OL}	Low-level output voltage	I_{OL} = 20 µA	2			0.1		0.1		0.1	V
		I_{OL} = 20 µA	4.5			0.1		0.1		0.1	V
		I_{OL} = 20 µA	6			0.1		0.1		0.1	V
	Low-level output voltage	I_{OL} = 4 mA	4.5			0.26		0.33		0.4	V
		I_{OL} = 5.2 mA	6			0.26		0.33		0.4	V
I_I	Input leakage current	V_I = V_{CC} or GND	6			±0.1		±1		±1	µA
I_{CC}	Supply current	V_I = V_{CC} or GND	6			8		80		160	µA
HCT TYPES											
V_{IH}	High-level input voltage		4.5 to 5.5	2			2		2		V
V_{IL}	Low-level input voltage		4.5 to 5.5			0.8		0.8		0.8	V
V_{OH}	High-level output voltage	I_{OH} = – 20 µA	4.5	4.4			4.4		4.4		V
	High-level output voltage	I_{OH} = – 4 mA	4.5	3.98			3.84		3.7		V
V_{OL}	Low-level output voltage	I_{OL} = 20 µA	4.5			0.1		0.1		0.1	V
	Low-level output voltage	I_{OH} = 4 mA	4.5			0.26		0.33		0.4	V
I_I	Input leakage current	V_I = V_{CC} and GND	5.5			±0.1		±1		±1	µA
I_{CC}	Supply current	V_I = V_{CC} and GND	5.5			8		80		160	µA
ΔI_{CC}	Additional supply current per input pin	A_0 - A_2 inputs held at V_{CC} – 2.1 V	4.5 to 5.5		100	540		675		735	µA
		$\overline{G}_0$ and $\overline{G}_1$ inputs held at V_{CC} – 2.1 V	4.5 to 5.5		100	450		562.5		612.5	µA
		G_2 input held at V_{CC} – 2.1 V	4.5 to 5.5		100	360		450		490	µA

(1) V_I = V_{IH} or V_{IL}, unless otherwise noted.

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5.5 Switching Characteristics[2]

Input t_t = 6ns. (See Parameter Measurement Information)

PARAMETER		TEST CONDITIONS	V_{CC} (V)	25°C			-40°C to 85°C		-55°C to 125°C		UNIT
				MIN	TYP	MAX	MIN	MAX	MIN	MAX	
HC TYPES											
t_{pd}	Address to output	C_L = 50pF	2			150		190		225	ns
			4.5		13[3]	30		38		45	
		C_L = 50pF	6			26		33		38	
	Strobe $\overline{G}_0$, $\overline{G}_1$, G_2 to output HC/HCT 138	C_L = 50pF	2			150		190		265	ns
			4.5			30		38		53	
			6			26		33		45	
t_t	Output transition time	C_L = 50pF	2			75		95		110	MHz
			4.5			15		19		22	
			6			13		16		19	
C_{pd}	Power dissipation capacitance[1]	C_L = 15pF	5		67						pF
C_i	Input capacitance					10		10		10	pF
HCT TYPES											
t_{pd}	Address to output	C_L = 50pF	4.5		14[3]	35		44		53	ns
	Strobe G_2 to output HC/HCT138	C_L = 50pF	4.5			35		44		53	ns
	Strobe $\overline{G}_0$, $\overline{G}_1$ to output HC/HCT238	C_L = 15pF	4.5			40		50		60	ns
t_t	Output transition time	C_L= 15pF	4.5			15		19		22	
C_{pd}	Power dissipation capacitance[1]	C_L = 15pF	5		67						pF
C_i	Input capacitance					10		10		10	pF

(1) C_{PD} is used to determine the dynamic power consumption, per gate.
(2) For details on power calculation, see SCAA035B
(3) C_L = 15pF and V_{CC} = 5

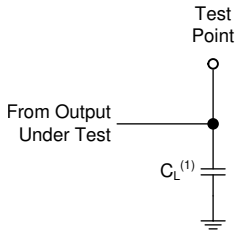
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6 Parameter Measurement Information

Phase relationships between waveforms were chosen arbitrarily. All input pulses are supplied by generators having the following characteristics: PRR ≤ 1 MHz, Z_O = 50 Ω, t_t < 6 ns.

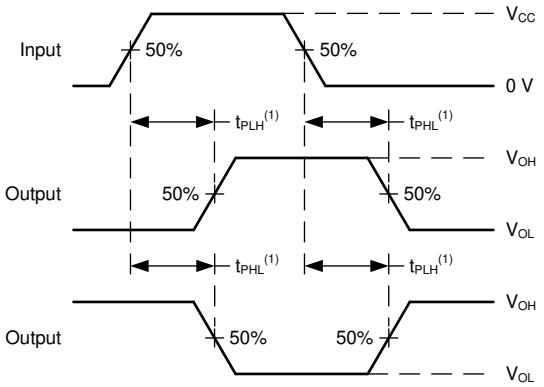
For clock inputs, f_{max} is measured when the input duty cycle is 50%.

The outputs are measured one at a time with one input transition per measurement.



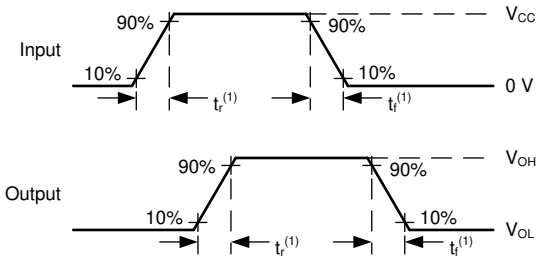
(1) C_L includes probe and test-fixture capacitance.

図 6-1. Load Circuit for Push-Pull Outputs



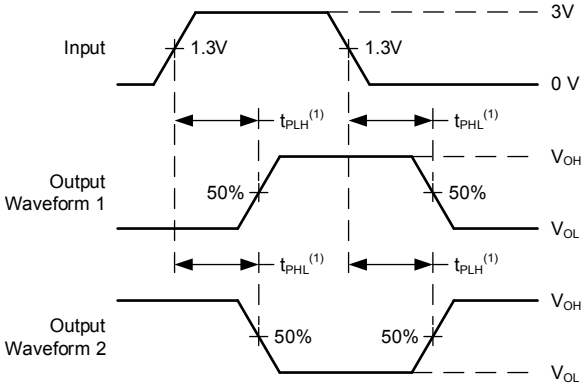
(1) The greater between t_{PLH} and t_{PHL} is the same as t_{pd}.

図 6-2. Voltage Waveforms, Propagation Delays for Standard CMOS Inputs



(1) The greater between t_r and t_f is the same as t_t.

図 6-3. Voltage Waveforms, Input and Output Transition Times for Standard CMOS Inputs



(1) The greater between t_{PLH} and t_{PHL} is the same as t_{pd}.

図 6-4. Voltage Waveforms, Propagation Delays for TTL-Compatible Inputs

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7 Detailed Description

7.1 Overview

The CDx4HC(T)138 and '238 are high speed silicon gate CMOS decoders well suited to memory address decoding or data routing applications. They contain a single 3:8 decoder.

The CDx4HC(T)138 and '238 have three address select inputs (A_2, A_1, and A_0). The circuit functions as a normal one-of-eight decoder.

Three strobe inputs (G_2, $\overline{G}_1$ and $\overline{G}_0$) are provided to simplify cascading and to facilitate demultiplexing. When any input strobe is active, all outputs are forced into the high state for the '138 function. When any input strobe is active, all outputs are forced into the low state for the '238 function.

The demultiplexing function is accomplished by first using the select inputs to choose the desired output, and then using one of the strobe inputs as the data input.

The outputs for the CDx4HC(T)138 are normally low when selected. The outputs for the CDxHC(T)238 are normally high when selected.

7.2 Functional Block Diagram

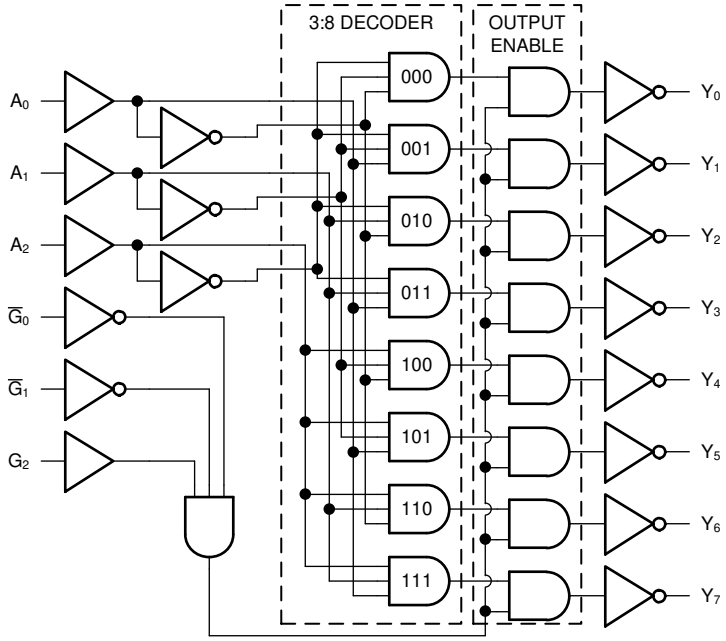


図 7-1. Functional Block Diagram '138

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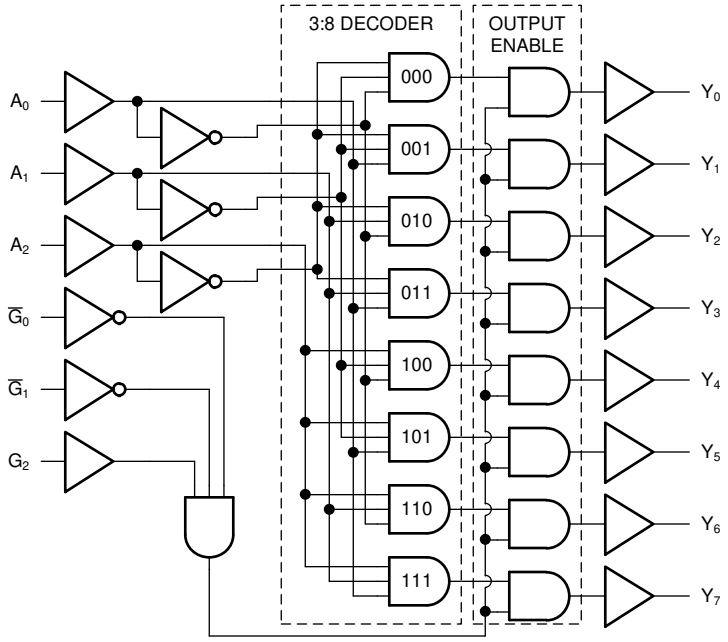


図 7-2. Functional Block Diagram '238

7.3 Device Functional Modes

表 7-1. Function Table 'HC138, 'HCT138

INPUTS						OUTPUTS							
STROBE			ADDRESS										
G2	$\overline{G1}$	$\overline{G0}$	A_2	A_1	A_0	Y_0	Y_1	Y_2	Y_3	Y_4	Y_5	Y_6	Y_7
X	X	H	X	X	X	H	H	H	H	H	H	H	H
L	X	X	X	X	X	H	H	H	H	H	H	H	H
X	H	X	X	X	X	H	H	H	H	H	H	H	H
H	L	L	L	L	L	L	H	H	H	H	H	H	H
H	L	L	L	L	H	H	L	H	H	H	H	H	H
H	L	L	L	H	L	H	H	L	H	H	H	H	H
H	L	L	L	H	H	H	H	H	L	H	H	H	H
H	L	L	H	L	L	H	H	H	H	L	H	H	H
H	L	L	H	L	H	H	H	H	H	H	L	H	H
H	L	L	H	H	L	H	H	H	H	H	H	L	H
H	L	L	H	H	H	H	H	H	H	H	H	H	L

H = High Voltage Level, L = Low Voltage Level, X = Don’t Care

表 7-2. Function Table 'HC238, 'HCT238

INPUTS						OUTPUTS							
STROBE			ADDRESS										
G2	$\overline{G1}$	$\overline{G0}$	A_2	A_1	A_0	Y_0	Y_1	Y_2	Y_3	Y_4	Y_5	Y_6	Y_7
X	X	H	X	X	X	L	L	L	L	L	L	L	L
L	X	X	X	X	X	L	L	L	L	L	L	L	L
X	H	X	X	X	X	L	L	L	L	L	L	L	L
H	L	L	L	L	L	H	L	L	L	L	L	L	L
H	L	L	L	L	H	L	H	L	L	L	L	L	L
H	L	L	L	H	L	L	L	H	L	L	L	L	L
H	L	L	L	H	H	L	L	L	H	L	L	L	L
H	L	L	H	L	L	L	L	L	L	H	L	L	L
H	L	L	H	L	H	L	L	L	L	L	H	L	L
H	L	L	H	H	L	L	L	L	L	L	L	H	L
H	L	L	H	H	H	L	L	L	L	L	L	L	H

H = High Voltage Level, L = Low Voltage Level, X = Don’t Care

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8 Power Supply Recommendations

The power supply can be any voltage between the minimum and maximum supply voltage rating located in the *Recommended Operating Conditions*. Each V_{CC} terminal should have a good bypass capacitor to prevent power disturbance. A 0.1-µF capacitor is recommended for this device. It is acceptable to parallel multiple bypass caps to reject different frequencies of noise. The 0.1-µF and 1-µF capacitors are commonly used in parallel. The bypass capacitor should be installed as close to the power terminal as possible for best results.

9 Layout

9.1 Layout Guidelines

When using multiple-input and multiple-channel logic devices inputs must not ever be left floating. In many cases, functions or parts of functions of digital logic devices are unused; for example, when only two inputs of a triple-input AND gate are used or only 3 of the 4 buffer gates are used. Such unused input pins must not be left unconnected because the undefined voltages at the outside connections result in undefined operational states. All unused inputs of digital logic devices must be connected to a logic high or logic low voltage, as defined by the input voltage specifications, to prevent them from floating. The logic level that must be applied to any particular unused input depends on the function of the device. Generally, the inputs are tied to GND or V_{CC}, whichever makes more sense for the logic function or is more convenient.

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10 Device and Documentation Support

TI offers an extensive line of development tools. Tools and software to evaluate the performance of the device, generate code, and develop solutions are listed below.

10.1 Documentation Support

10.1.1 Related Documentation

10.2 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. Click on *Subscribe to updates* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

10.3 サポート・リソース

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10.4 Trademarks

TI E2E™ is a trademark of Texas Instruments.
すべての商標は、それぞれの所有者に帰属します。

10.5 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

10.6 Glossary

TI Glossary	This glossary lists and explains terms, acronyms, and definitions.

11 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

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PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
5962-8688401EA	ACTIVE	CDIP	J	16	25	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962-8688401EA CD54HC238F3A	Samples
CD54HC138F	ACTIVE	CDIP	J	16	25	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	CD54HC138F	Samples
CD54HC138F3A	ACTIVE	CDIP	J	16	25	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	8406201EA CD54HC138F3A	Samples
CD54HC238F3A	ACTIVE	CDIP	J	16	25	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962-8688401EA CD54HC238F3A	Samples
CD54HCT138F	ACTIVE	CDIP	J	16	25	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	CD54HCT138F	Samples
CD54HCT138F3A	ACTIVE	CDIP	J	16	25	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	8550401EA CD54HCT138F3A	Samples
CD54HCT238F3A	ACTIVE	CDIP	J	16	25	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962-8974501EA CD54HCT238F3A	Samples
CD74HC138E	ACTIVE	PDIP	N	16	25	RoHS & Green	NIPDAU	N / A for Pkg Type	-55 to 125	CD74HC138E	Samples
CD74HC138M96	ACTIVE	SOIC	D	16	2500	RoHS & Green	NIPDAU | SN	Level-1-260C-UNLIM	-55 to 125	HC138M	Samples
CD74HC138M96E4	ACTIVE				2500	TBD	Call TI	Call TI	-55 to 125		Samples
CD74HC238E	ACTIVE	PDIP	N	16	25	RoHS & Green	NIPDAU	N / A for Pkg Type	-55 to 125	CD74HC238E	Samples
CD74HC238EE4	ACTIVE	PDIP	N	16	25	RoHS & Green	NIPDAU	N / A for Pkg Type	-55 to 125	CD74HC238E	Samples
CD74HC238M96	ACTIVE	SOIC	D	16	2500	RoHS & Green	NIPDAU | SN	Level-1-260C-UNLIM	-55 to 125	HC238M	Samples
CD74HC238NSR	ACTIVE	SO	NS	16	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	HC238M	Samples
CD74HC238PWR	ACTIVE	TSSOP	PW	16	2000	RoHS & Green	NIPDAU | SN	Level-1-260C-UNLIM	-55 to 125	HJ238	Samples
CD74HCT138E	ACTIVE	PDIP	N	16	25	RoHS & Green	NIPDAU	N / A for Pkg Type	-55 to 125	CD74HCT138E	Samples
CD74HCT138M96	ACTIVE	SOIC	D	16	2500	RoHS & Green	NIPDAU | SN	Level-1-260C-UNLIM	-55 to 125	HCT138M	Samples
CD74HCT238E	ACTIVE	PDIP	N	16	25	RoHS & Green	NIPDAU	N / A for Pkg Type	-55 to 125	CD74HCT238E	Samples

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
CD74HCT238M96	ACTIVE	SOIC	D	16	2500	RoHS & Green	NIPDAU | SN	Level-1-260C-UNLIM	-55 to 125	HCT238M	Samples
CD74HCT238PWR	ACTIVE	TSSOP	PW	16	2000	RoHS & Green	NIPDAU | SN	Level-1-260C-UNLIM	-55 to 125	HK238	Samples

(1) The marketing status values are defined as follows:
ACTIVE: Product device recommended for new designs.
LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.
NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.
PREVIEW: Device has been announced but is not in production. Samples may or may not be available.
OBSOLETE: TI has discontinued the production of the device.

(2) **RoHS:** TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".
RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.
Green: TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

OTHER QUALIFIED VERSIONS OF CD54HC138, CD54HC238, CD54HCT138, CD54HCT238, CD74HC138, CD74HC238, CD74HCT138, CD74HCT238 :

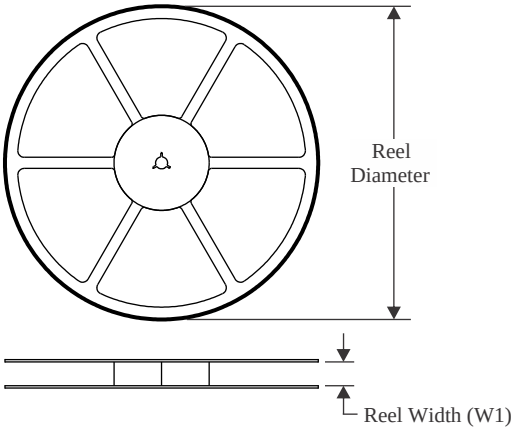
- Catalog : CD74HC138, CD74HC238, CD74HCT138, CD74HCT238
- Automotive : CD74HC138-Q1, CD74HC138-Q1
- Military : CD54HC138, CD54HC238, CD54HCT138, CD54HCT238

NOTE: Qualified Version Definitions:

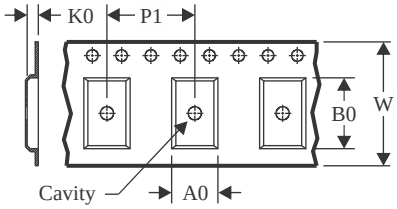
- Catalog - TI's standard catalog product
- Automotive - Q100 devices qualified for high-reliability automotive applications targeting zero defects
- Military - QML certified for Military and Defense Applications

TAPE AND REEL INFORMATION

REEL DIMENSIONS

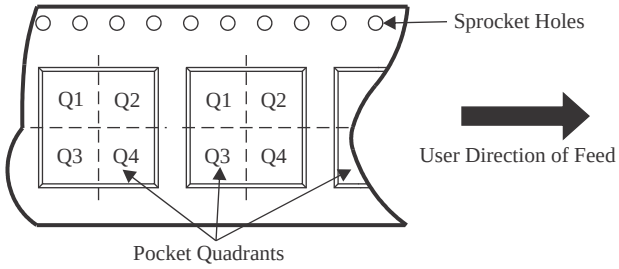


TAPE DIMENSIONS



A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

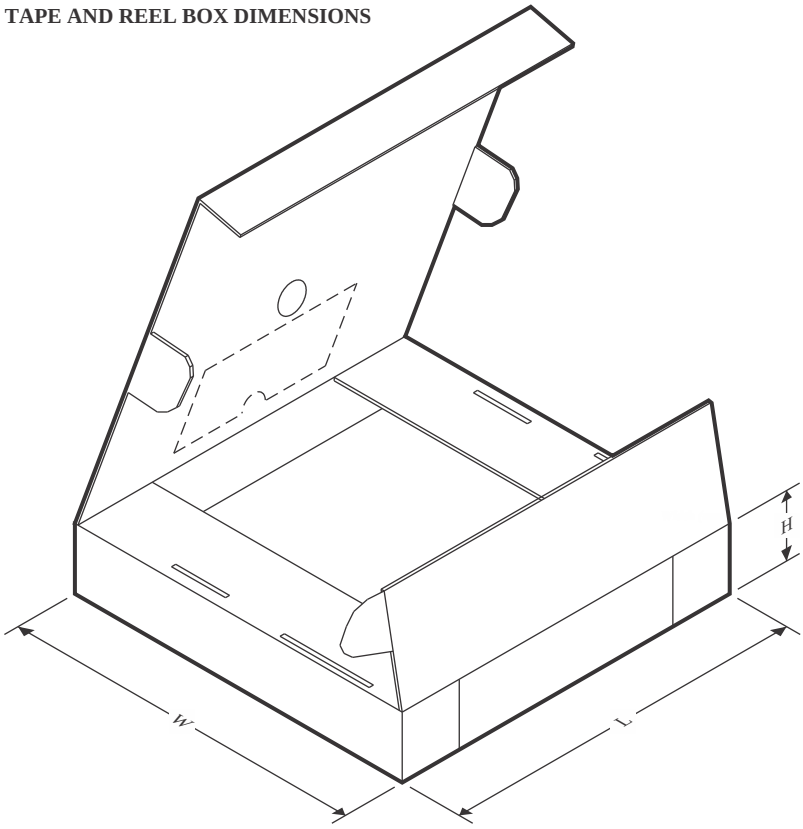
QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
CD74HC138M96	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1
CD74HC138M96	SOIC	D	16	2500	330.0	16.4	6.6	9.3	2.1	8.0	16.0	Q1
CD74HC238M96	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1
CD74HC238NSR	SO	NS	16	2000	330.0	16.4	8.2	10.5	2.5	12.0	16.0	Q1
CD74HC238PWR	TSSOP	PW	16	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
CD74HC238PWR	TSSOP	PW	16	2000	330.0	12.4	6.85	5.45	1.6	8.0	12.0	Q1
CD74HC238PWR	TSSOP	PW	16	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
CD74HCT138M96	SOIC	D	16	2500	330.0	16.4	6.6	9.3	2.1	8.0	16.0	Q1
CD74HCT138M96	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1
CD74HCT238M96	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1
CD74HCT238PWR	TSSOP	PW	16	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
CD74HCT238PWR	TSSOP	PW	16	2000	330.0	12.4	6.85	5.45	1.6	8.0	12.0	Q1
CD74HCT238PWR	TSSOP	PW	16	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1

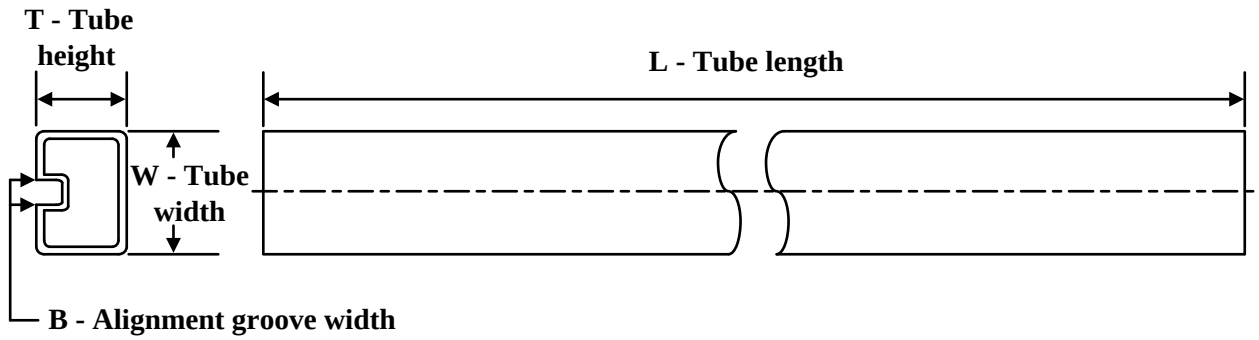
TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
CD74HC138M96	SOIC	D	16	2500	356.0	356.0	35.0
CD74HC138M96	SOIC	D	16	2500	366.0	364.0	50.0
CD74HC238M96	SOIC	D	16	2500	356.0	356.0	35.0
CD74HC238NSR	SO	NS	16	2000	356.0	356.0	35.0
CD74HC238PWR	TSSOP	PW	16	2000	356.0	356.0	35.0
CD74HC238PWR	TSSOP	PW	16	2000	366.0	364.0	50.0
CD74HC238PWR	TSSOP	PW	16	2000	356.0	356.0	35.0
CD74HCT138M96	SOIC	D	16	2500	366.0	364.0	50.0
CD74HCT138M96	SOIC	D	16	2500	356.0	356.0	35.0
CD74HCT238M96	SOIC	D	16	2500	356.0	356.0	35.0
CD74HCT238PWR	TSSOP	PW	16	2000	356.0	356.0	35.0
CD74HCT238PWR	TSSOP	PW	16	2000	366.0	364.0	50.0
CD74HCT238PWR	TSSOP	PW	16	2000	356.0	356.0	35.0

TUBE



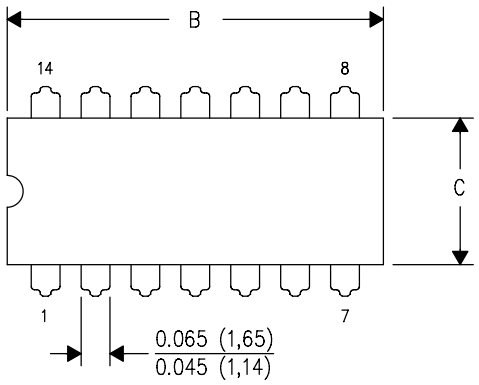
*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (µm)	B (mm)
CD74HC138E	N	PDIP	16	25	506	13.97	11230	4.32
CD74HC138E	N	PDIP	16	25	506	13.97	11230	4.32
CD74HC238E	N	PDIP	16	25	506	13.97	11230	4.32
CD74HC238E	N	PDIP	16	25	506	13.97	11230	4.32
CD74HC238EE4	N	PDIP	16	25	506	13.97	11230	4.32
CD74HC238EE4	N	PDIP	16	25	506	13.97	11230	4.32
CD74HCT138E	N	PDIP	16	25	506	13.97	11230	4.32
CD74HCT138E	N	PDIP	16	25	506	13.97	11230	4.32
CD74HCT238E	N	PDIP	16	25	506	13.97	11230	4.32
CD74HCT238E	N	PDIP	16	25	506	13.97	11230	4.32

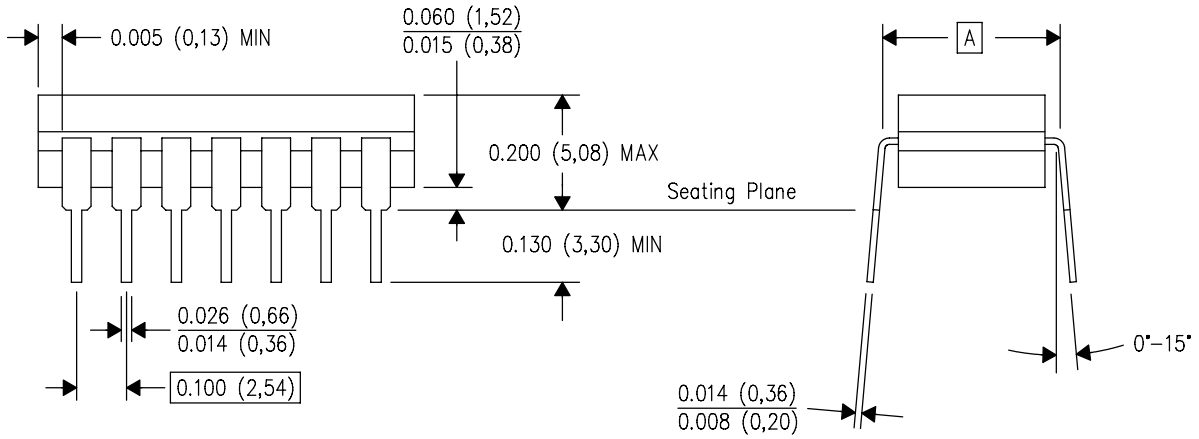
J (R–GDIP–T**)

14 LEADS SHOWN

CERAMIC DUAL IN–LINE PACKAGE



DIM \ PINS **	14	16	18	20
A	0.300 (7,62) BSC	0.300 (7,62) BSC	0.300 (7,62) BSC	0.300 (7,62) BSC
B MAX	0.785 (19,94)	.840 (21,34)	0.960 (24,38)	1.060 (26,92)
B MIN	—	—	—	—
C MAX	0.300 (7,62)	0.300 (7,62)	0.310 (7,87)	0.300 (7,62)
C MIN	0.245 (6,22)	0.245 (6,22)	0.220 (5,59)	0.245 (6,22)



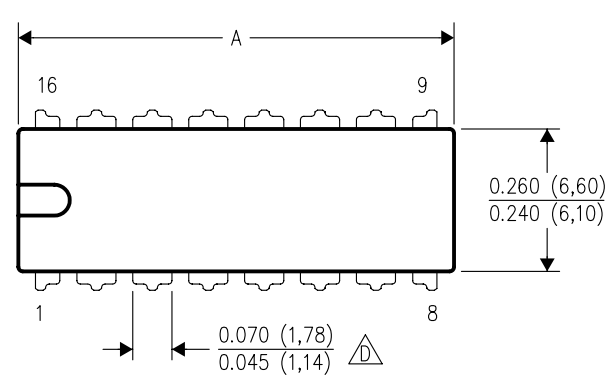
4040083/F 03/03

NOTES:
A. All linear dimensions are in inches (millimeters).
B. This drawing is subject to change without notice.
C. This package is hermetically sealed with a ceramic lid using glass frit.
D. Index point is provided on cap for terminal identification only on press ceramic glass frit seal only.
E. Falls within MIL STD 1835 GDIP1–T14, GDIP1–T16, GDIP1–T18 and GDIP1–T20.

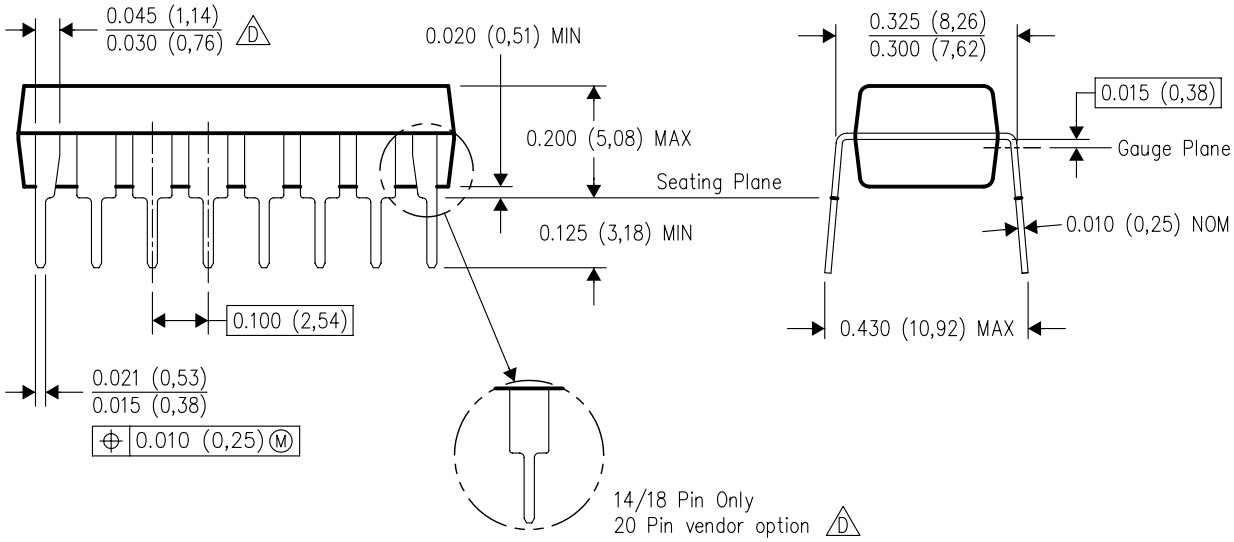
N (R–PDIP–T**)

PLASTIC DUAL–IN–LINE PACKAGE

16 PINS SHOWN

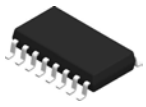


DIM \ PINS **	14	16	18	20
A MAX	0.775 (19,69)	0.775 (19,69)	0.920 (23,37)	1.060 (26,92)
A MIN	0.745 (18,92)	0.745 (18,92)	0.850 (21,59)	0.940 (23,88)
MS–001 VARIATION (C)	AA	BB	AC	AD



4040049/E 12/2002

NOTES:
A. All linear dimensions are in inches (millimeters).
B. This drawing is subject to change without notice.
C. Falls within JEDEC MS–001, except 18 and 20 pin minimum body length (Dim A).
D. The 20 pin end lead shoulder width is a vendor option, either half or full width.

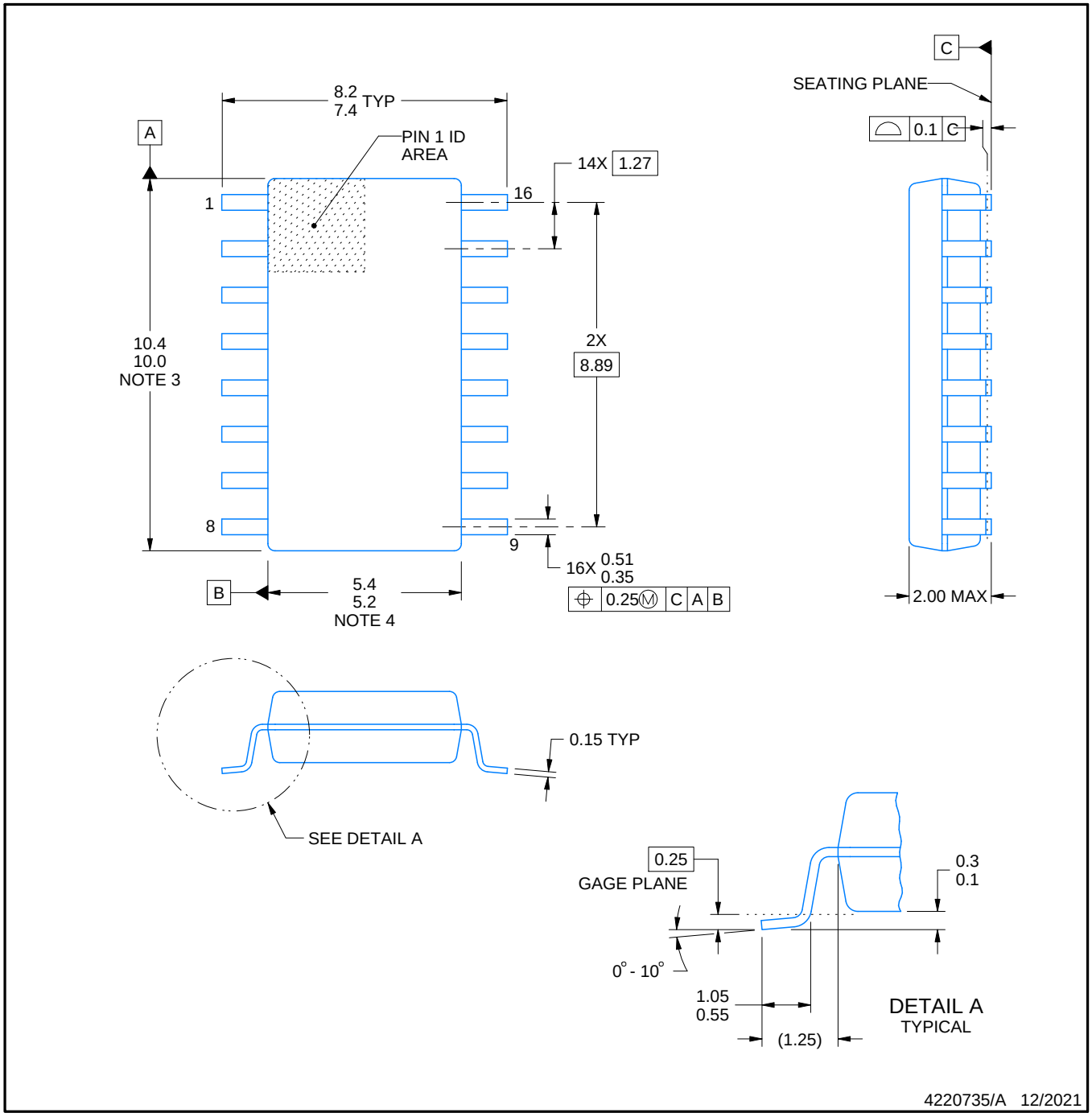


PACKAGE OUTLINE

NS0016A

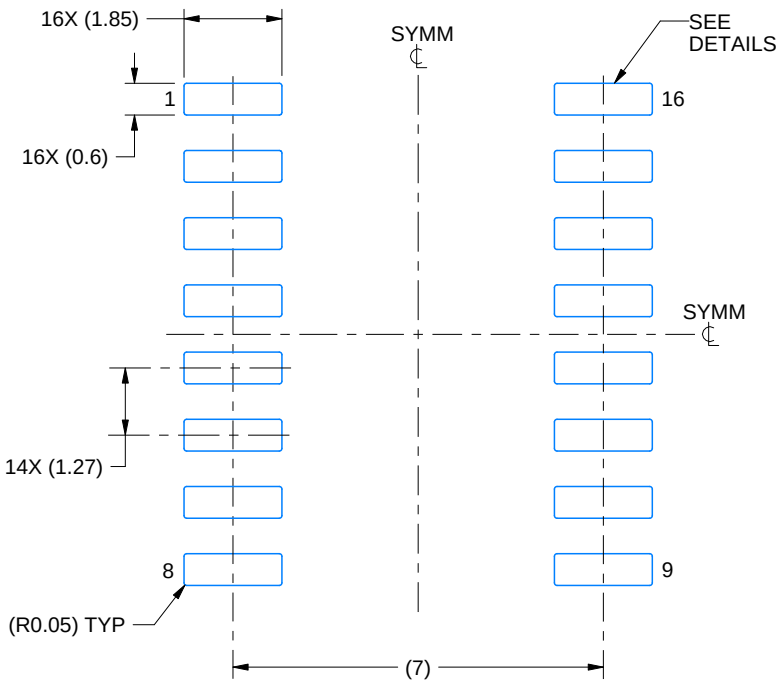
SOP - 2.00 mm max height

SOP

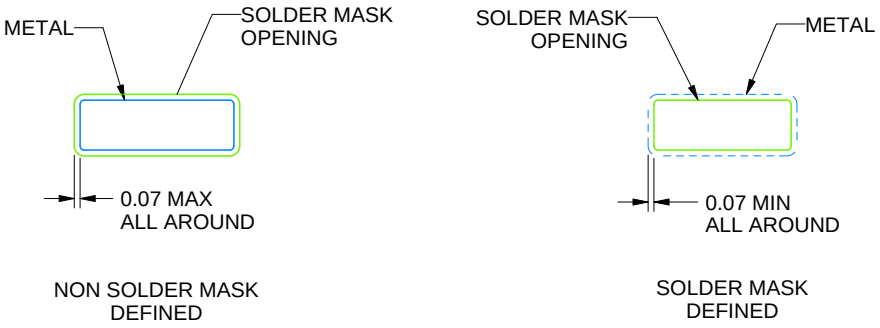


NOTES:

1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm, per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm, per side.



LAND PATTERN EXAMPLE
SCALE:7X



NON SOLDER MASK
DEFINED

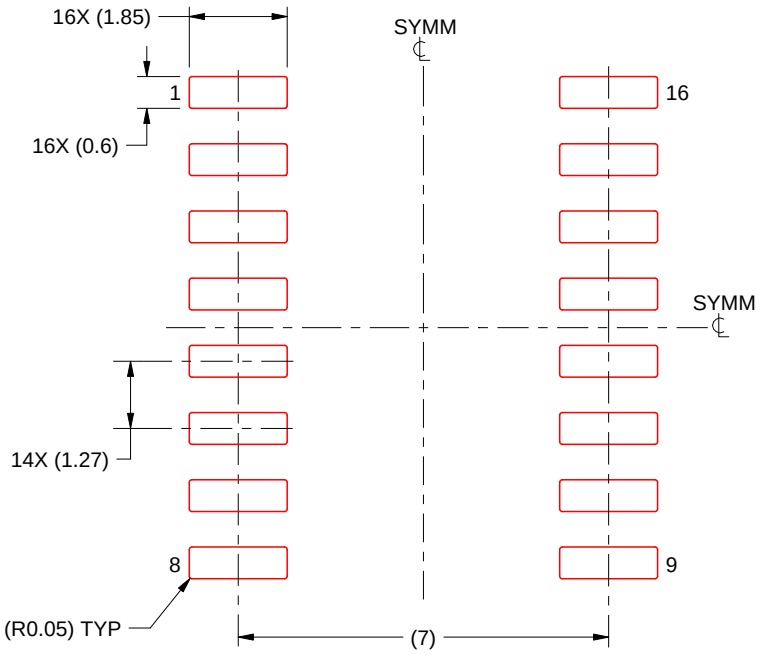
SOLDER MASK
DEFINED

SOLDER MASK DETAILS

4220735/A 12/2021

NOTES: (continued)

5. Publication IPC-7351 may have alternate designs.
6. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



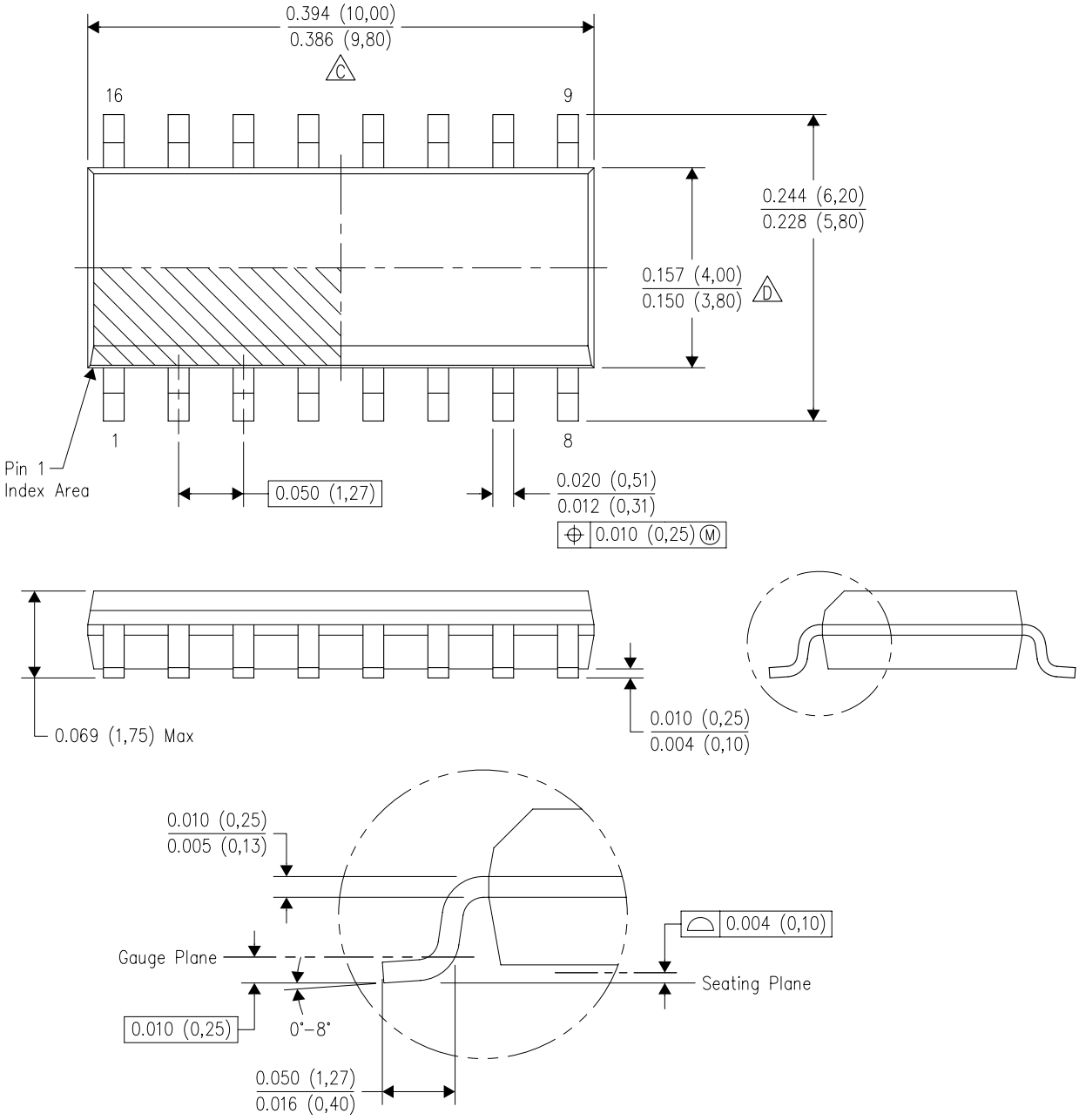
SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE:7X

4220735/A 12/2021

NOTES: (continued)

7. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
8. Board assembly site may have different recommendations for stencil design.

D (R–PDSO–G16) PLASTIC SMALL OUTLINE



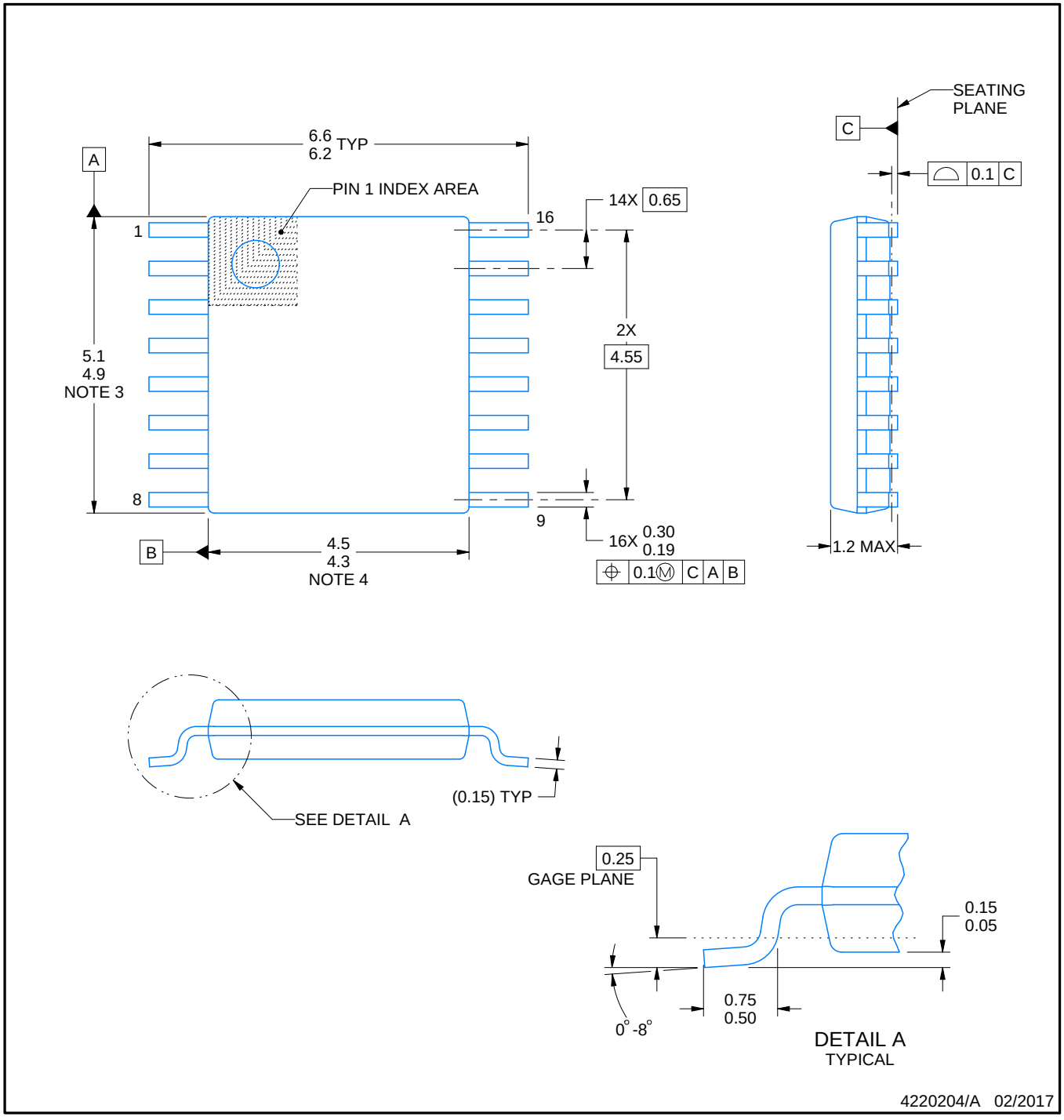
NOTES:
A. All linear dimensions are in inches (millimeters).
B. This drawing is subject to change without notice.
C. Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
D. Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
E. Reference JEDEC MS–012 variation AC.

PACKAGE OUTLINE

PW0016A

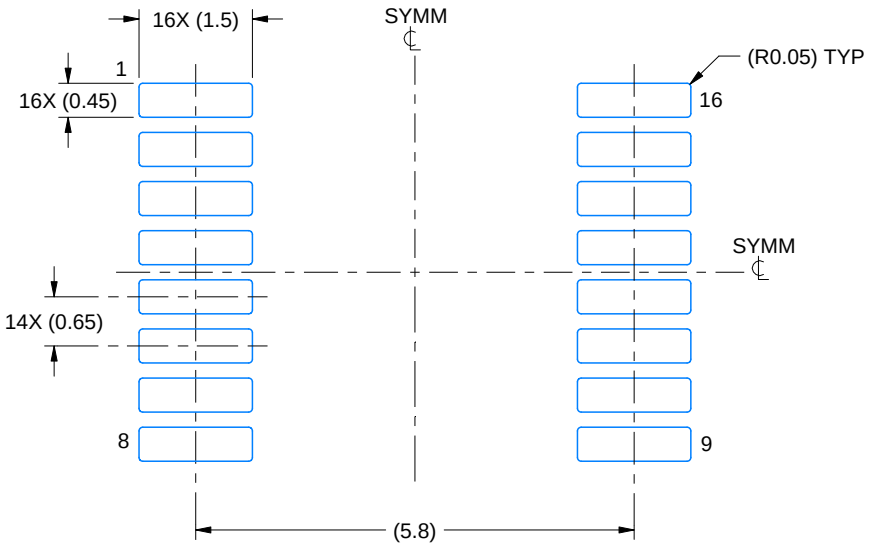
TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE

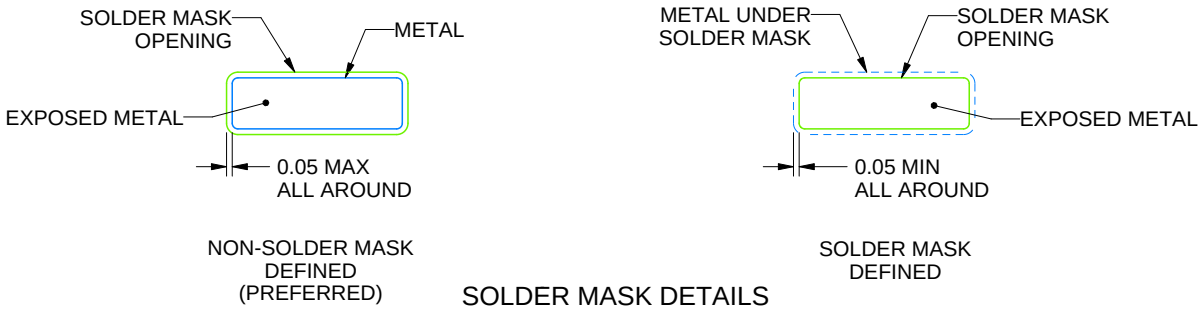


NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
5. Reference JEDEC registration MO-153.



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE: 10X

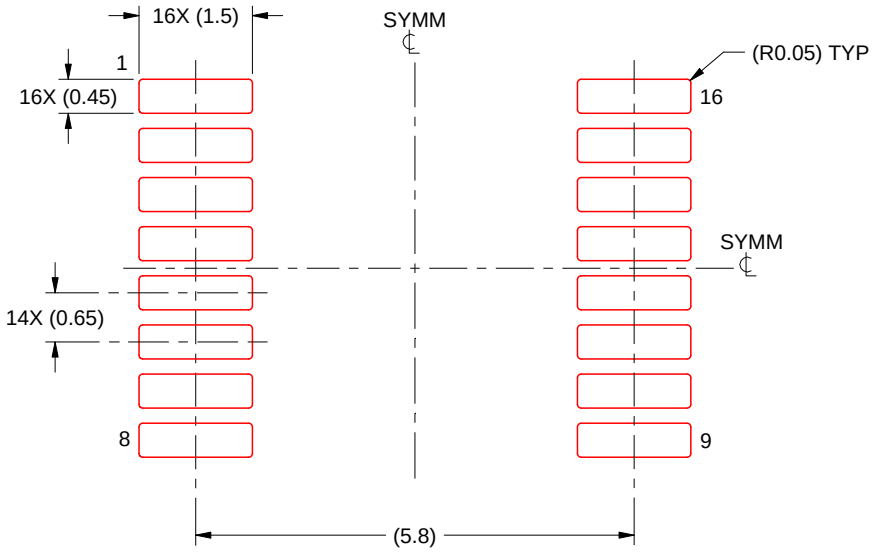


SOLDER MASK DETAILS

4220204/A 02/2017

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE: 10X

4220204/A 02/2017

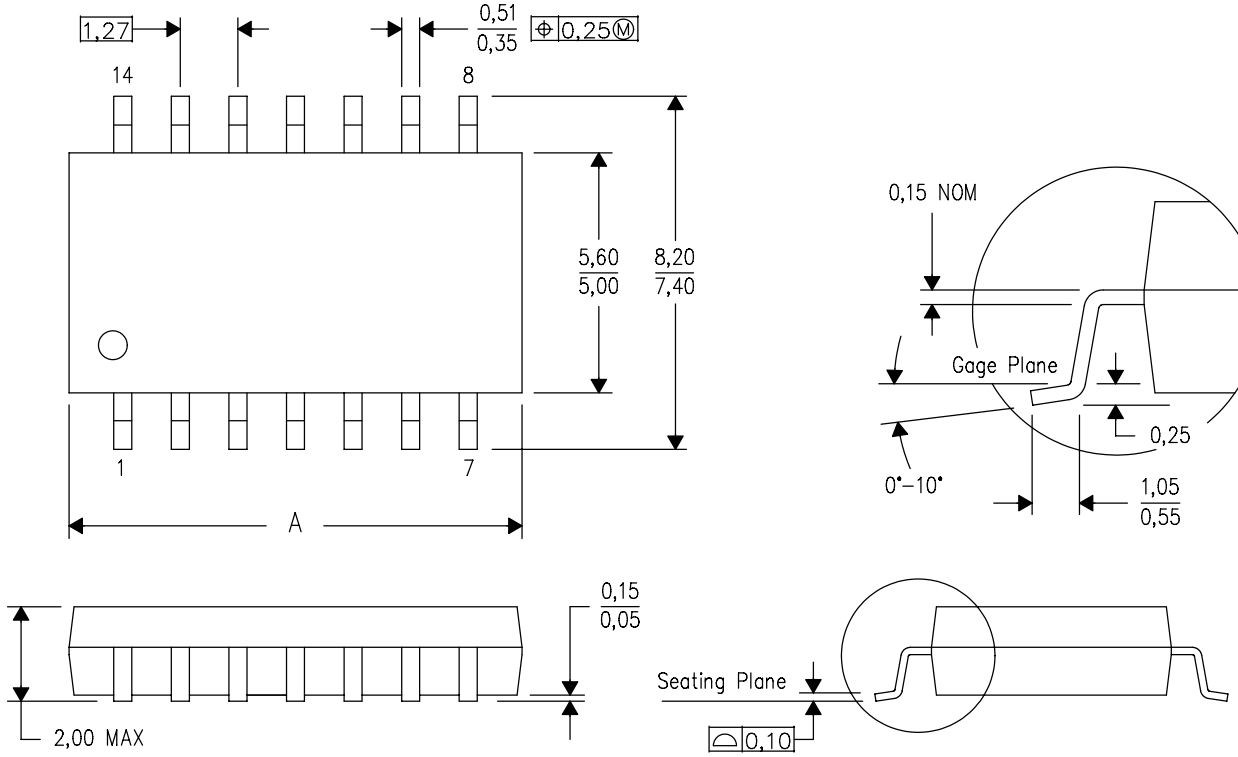
NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

MECHANICAL DATA

NS (R-PDSO-G)** **PLASTIC SMALL-OUTLINE PACKAGE**

14-PINS SHOWN



DIM \ PINS **	14	16	20	24
A MAX	10,50	10,50	12,90	15,30
A MIN	9,90	9,90	12,30	14,70

4040062/C 03/03

NOTES:
A. All linear dimensions are in millimeters.
B. This drawing is subject to change without notice.
C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.

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